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	APPLICANT(s)	
	Hans W. P. KOOPS et al.	
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EXAMINER	Q2	DATE CONSIDERED 9/28/03
EXAMINER: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and		

Authority).

**Cited on German Patent Office Search Report (copy of reference and corresponding English abstract and search report enclosed).